TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (Ultra-High-Speed U-MOSⅢ)

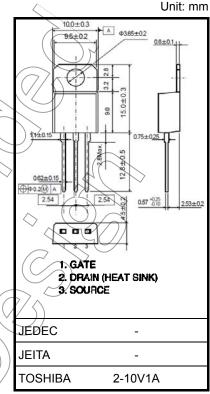
TK60D08J1

Switching Regulator Application

- High-Speed switching
- Small gate charge: Q_g = 86 nC (typ.)
- Low drain-source ON resistance: $R_{DS (ON)} = 6.2 \text{ m}\Omega$ (typ.)
- High forward transfer admittance: |Y_{fs}| = 120 S (typ.)
- Low leakage current: $I_{DSS} = 10 \mu A \text{ (max) (V}_{DS} = 75 \text{ V)}$
- Enhancement-mode: V_{th} = 1.1 to 2.3 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics			Symbol	Rating	thit	
Drain-source voltage			V_{DSS}	75	V	
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)			V_{DGR}	75	</td	
Gate-source voltage			V_{GSS}	±20	V	
Drain current	DC	(Note 1)	I _D	60	Α	
	Pulse	(Note 1)	I _{DP}	240	A	
Drain power dissipation (Tc = 25°C)			P _D	140	W	
Single pulse avalanche energy (Note 2)			EAS	498) E	
Avalanche current			I _{AR})) 60	Α	
Repetitive avalanche energy (Note 3)			EAR	9.2	mJ	
Channel temperature			T _{ch}	150	7,¢	
Storage temperature range			___\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	-55 to 450	ွှိ	
			/ 11		_ /	



Weight: 1.35 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	0.89	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	83.3	°C/W

Internal Connection



- Note 1: Ensure that the channel & lead temperature does not exceed 150°C.
- Note 2: $V_{DD} = 25 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}$, $L = 200 \ \mu\text{H}$, $I_{AR} = 60 \ \text{A}$, $R_G = 1 \Omega$
- Note 3: Repetitive rating; pulse width limited by maximum channel temperature.

This transistor is an electrostatic sensitive device. Handle with care.

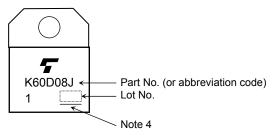
Electrical Characteristics (Ta = 25°C)

Chara	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μΑ
Drain cut-OFF cu	rrent	I _{DSS}	V _{DS} = 75 V, V _{GS} = 0 V	_	_	10	μА
Drain-source breakdown voltage		V (BR) DSS	I _D = 10 mA, V _{GS} = 0 V	75	_	_	V
		V (BR) DSX	I _D = 10 mA, V _{GS} = -20 V		/	_	V
Gate threshold voltage		V _{th}	V _{DS} = 10 V, I _D = 1 mA	/11))	2.3	٧
Drain-source ON resistance		R _{DS (ON)}	V _{GS} = 4.5 V, I _D = 30A	75	7.1	9.3	- mΩ
			V _{GS} = 10 V, I _D = 30A	\mathcal{A}	6.2	7.8	
Forward transfer admittance		Y _{fs}	V _{DS} = 10 V, I _D = 30 A	60	120	_	S
Input capacitance		C _{iss}		_	5450	_	
Reverse transfer capacitance		C _{rss}	V _{DS} = 10V, V _{GS} = 0 V, f = 1 MHz	_	320	/	pF
Output capacitance		Coss		_ /	1260	\searrow	
Switching time	Rise time	t _r	10 V ID 30 A VOUT	_(5		ns
	Turn-ON time	t _{on}	V _{GS} 0 V OUT R _L = 1 Ω	7	>20	/ —	
	Fall time	t _f	V _{DD} ≈ 30 (V / ⟨		15		
	Turn-OFF time	t _{off}	Duty ≤ 1%, t _w = 10 μs	_	96	_	
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD} \simeq 60 \text{ V}, V_{GS} = 5 \text{ V}, V_{D} = 60 \text{ A}$	_	48	_	
			$V_{DD} \simeq 60 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 60 \text{ A}$		86		
Gate-source charge 1		Q _{gs1}			16	_	nC
Gate-drain ("miller") charge		Qgd	$V_{DD} \simeq 60 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 60 \text{ A}$	_	20	_	
Gate switch charge		Øsw			27		

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	<u> </u>	_	_	60	Α
Pulse drain reverse current (Note 1)	IDRP	_	_	_	240	Α
Forward voltage (diode)	VDSF	I _{DR} = 60 A, V _{GS} = 0 V	_	-0.9	-1.2	٧
Reverse recovery time	tin	$I_{DR} = 60 \text{ A}, V_{GS} = 0 \text{ V},$	_	63	_	ns
Reverse recovery charge	Q _{rr}	dI _{DR} /dt = 50 A/μs	_	63	_	nC

Marking



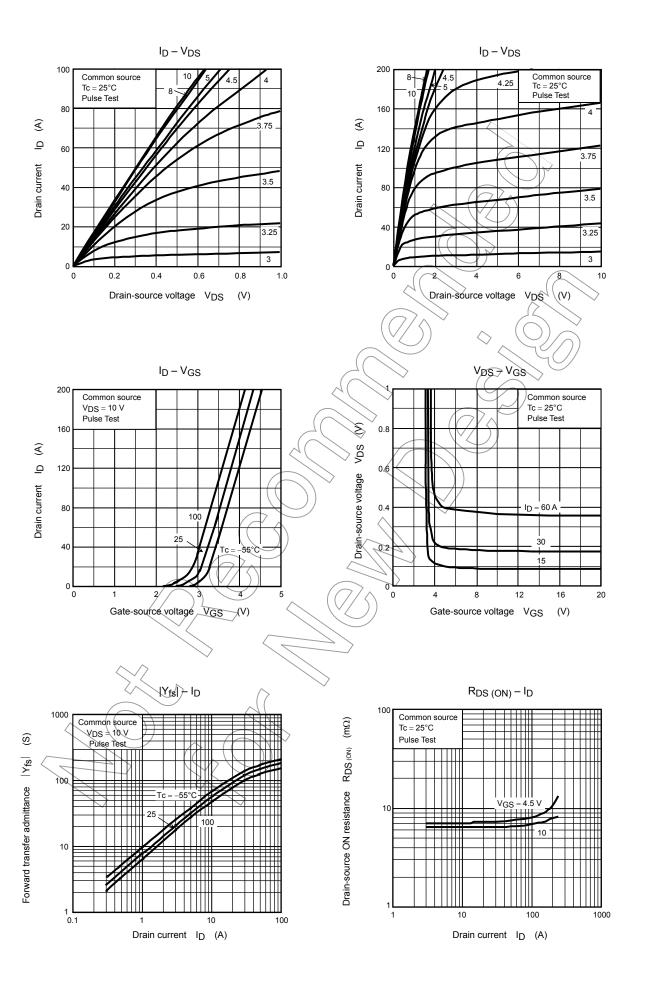
Note 4: A line under a Lot No. identifies the indication of product Labels.

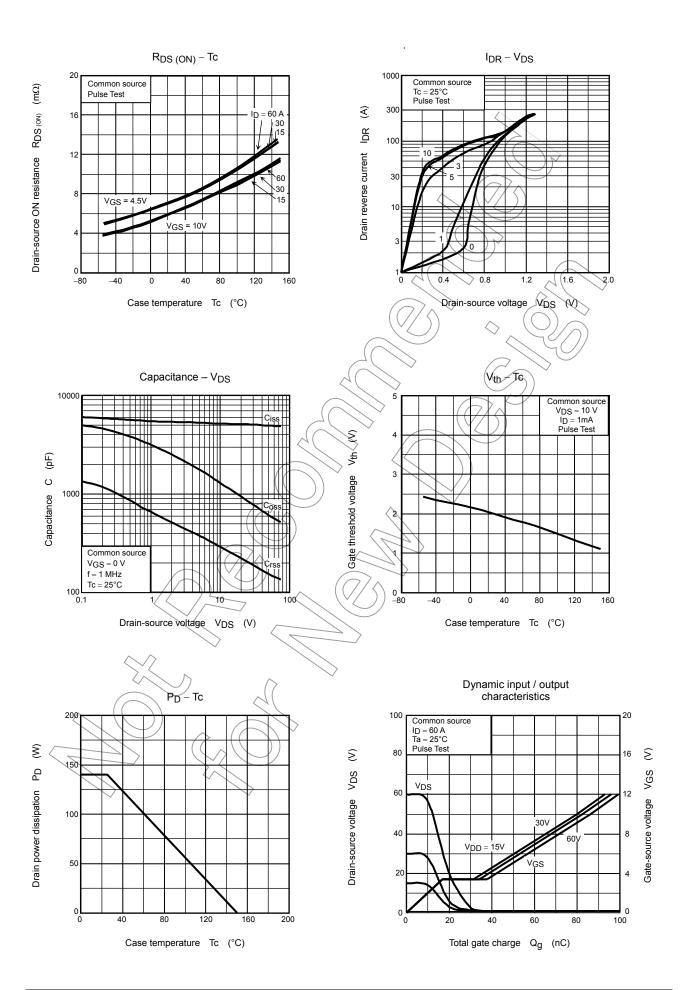
Not underlined: [[Pb]]/INCLUDES > MCV

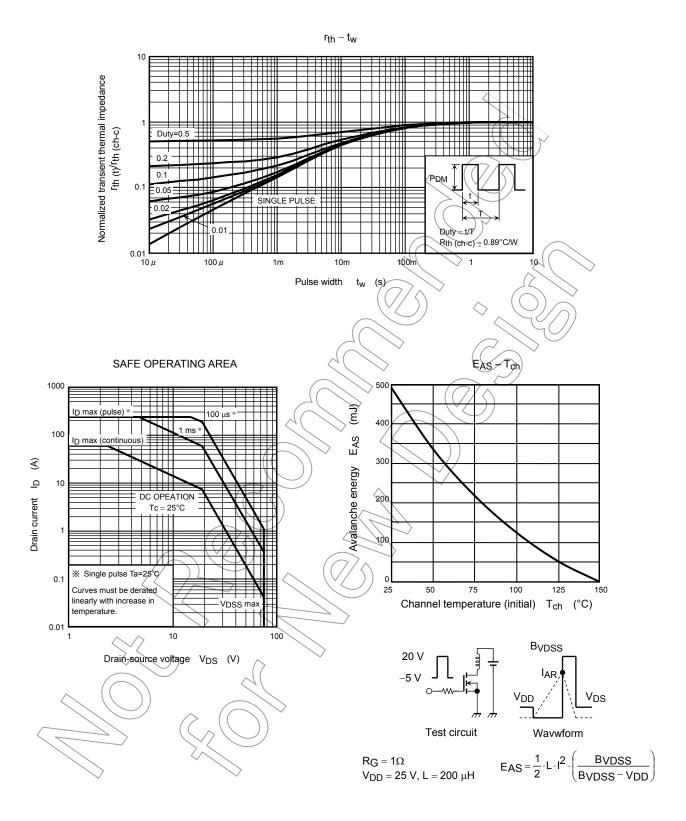
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

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